## BFR30LT1, BFR31LT1

## **JFET Amplifiers**

**N**–Channel

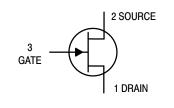
### Features

• Pb–Free Package is Available



### ON Semiconductor®

http://onsemi.com



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	25	Vdc
Gate-Source Voltage	$V_{GS}$	25	Vdc

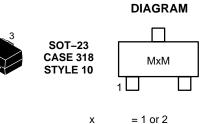
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1. Device mounted on FR4 glass epoxy printed circuit board using the recommended footprint.

2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.



Μ

= Date Code

MARKING

### **ORDERING INFORMATION**

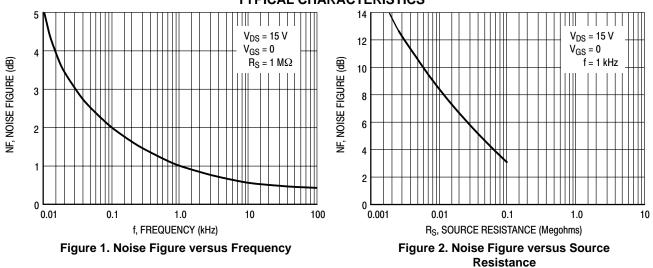
Device	Package	Shipping <sup>†</sup>
BFR30LT1	SOT-23	3000/Tape & Reel
BFR30LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
BFR31LT1	SOT-23	3000/Tape & Reel
BFR31LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

<sup>+</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### BFR30LT1, BFR31LT1

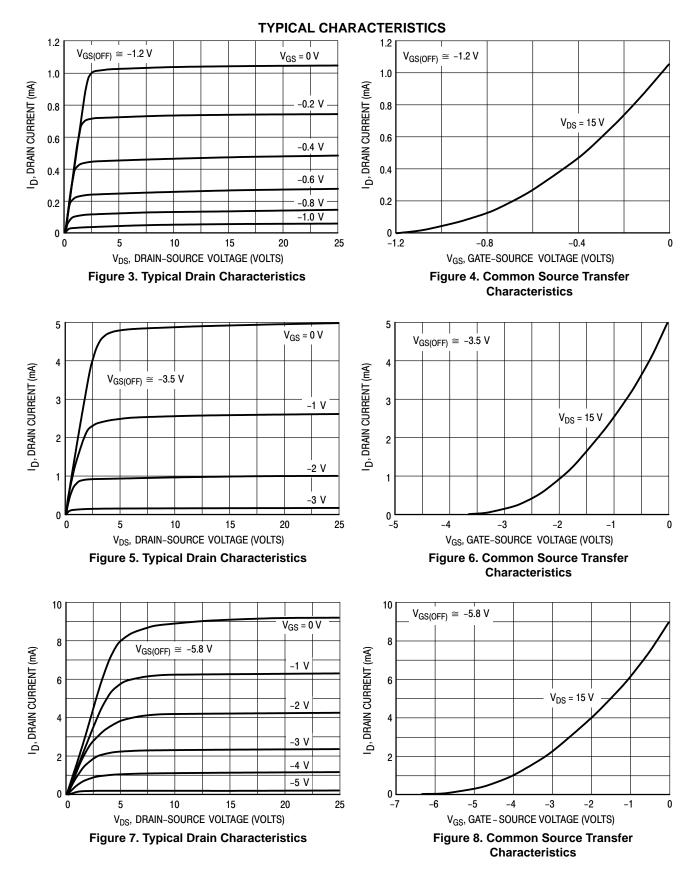
### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic			Symbol	Min	Max	Unit
OFF CHARACTERISTICS						
Gate Reverse Current	$(V_{GS} = 10 \text{ Vdc}, V_{DS} = 0)$		I <sub>GSS</sub>	-	0.2	nAdc
Gate Source Cutoff Voltage	$(I_D = 0.5 \text{ nAdc}, V_{DS} = 10 \text{ Vdc})$	BFR30 BFR31	V <sub>GS(OFF)</sub>	-	5.0 2.5	Vdc
Gate Source Voltage	$(I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ Vdc})$ $(I_D = 50 \mu \text{Adc}, V_{DS} = 10 \text{ Vdc})$	BFR30 BFR31 BFR30 BFR31	V <sub>GS</sub>	-0.7 - - -	-3.0 -1.3 -4.0 -2.0	Vdc
ON CHARACTERISTICS					-	-
Zero-Gate-Voltage Drain Current $(V_{DS} = 10 \text{ Vdc}, V_{GS} = 0)$ BFR30 BFR31			I <sub>DSS</sub>	4.0 1.0	10 5.0	mAdc
SMALL-SIGNAL CHARACTE	RISTICS					
Forward Transconductance ( $I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ Vol}$ ( $I_D = 200 \mu \text{Adc}, V_{DS} = 10 \text{ Vol}$		BFR30 BFR31 BFR30 BFR31	Yfs	1.0 1.5 0.5 0.75	4.0 4.5 -	mmhos
Output Admittance $(I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ V}_{OS}$ $(I_D = 200 \mu \text{Adc}, V_{DS} = 10 \text{ V}_{OS}$	. ,	BFR30 BFR31	Y <sub>os</sub>	40 20	25 15	µmhos
Input Capacitance	$(I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ V})$ $(I_D = 200 \mu\text{Adc}, V_{DS} = 10 \text{ V})$		C <sub>iss</sub>		5.0 4.0	pF
Reverse Transfer Capacitance	e $(I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ V})$ $(I_D = 200 \mu \text{Adc}, V_{DS} = 10 \text{ V})$		C <sub>rss</sub>	-	1.5 1.5	pF



### **TYPICAL CHARACTERISTICS**

### BFR30LT1, BFR31LT1



Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I<sub>DSS</sub> units reduces I<sub>DSS</sub>.

### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

3

TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

## onsemi



SCALE 4:1

A\_\_\_\_ ' A1SOT-23 (TO-236) CASE 318 ISSUE AT

0.25

-L1

DETAIL A

END VIEW

DATE 01 MAR 2023

NDTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIM	IETERS		INCHES		
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*



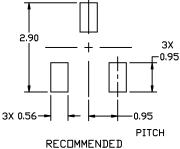


XXX = Specific Device Code

M = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

### **STYLES ON PAGE 2**

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### MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

# onsemi

### SOT-23 (TO-236) CASE 318 ISSUE AT

### DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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